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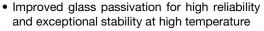
Vishay Semiconductors

Medium Power Phase Control Thyristors (Stud Version), 16 A



PRIMARY CHARACTERISTICS				
I _{T(AV)}	16 A			
V _{DRM} /V _{RRM}	100 V, 200 V, 400 V, 600 V, 800 V, 1000 V, 1200 V			
V_{TM}	1.75 V			
I _{GT}	60 mA			
T _J	-65 °C to +125 °C			
Package	TO-48 (TO-208AA)			
Circuit configuration	Single SCR			

FEATURES





- High dl/dt and dV/dt capabilities
- Standard package
- · Low thermal resistance
- · Metric threads version available
- Types up to 1200 V V_{DRM}/V_{RRM}
- Designed and qualified for industrial and consumer level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Medium power switching
- · Phase control applications

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
1		16	А			
I _{T(AV)}	T _C	85	°C			
I _{T(RMS)}		35	A			
I _{TSM}	50 Hz	340	Δ.			
	60 Hz	360	A A			
I ² t	50 Hz	574	A2-			
	60 Hz	524	— A ² s			
V _{DRM} /V _{RRM}		100 to 1200	V			
t _q	Typical	110	μs			
T _J		-65 to +125	°C			

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE ⁽¹⁾ V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE ⁽²⁾ V	$\begin{aligned} I_{DRM}/I_{RRM} & \text{MAXIMUM} \\ \text{AT } T_J = T_J & \text{MAXIMUM} \\ & \text{mA} \end{aligned}$			
	10	100	150	20			
	20	200	300				
	40	400	500				
VS-16RIA	60	600	700	10			
	80	800	900	10			
	100	1000	1100				
	120	1200	1300				

Notes

⁽¹⁾ Units may be broken over non-repetitively in the off-state direction without damage, if dl/dt does not exceed 20 A/µs

 $[\]ensuremath{^{(2)}}$ For voltage pulses with $t_p \leq 5 \ ms$



ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL		TEST CONDITIONS		VALUES	UNITS
Maximum average on-state current	I _{T(AV)}	180° sinusoi	180° sinusoidal conduction		16	Α
at case temperature	· (AV)		aa. 55aa551.		85	°C
Maximum RMS on-state current	I _{T(RMS)}				35	Α
		t = 10 ms	No voltage		340	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		360	۸
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}		285	Α
		t = 8.3 ms	reapplied	Sinusoidal half wave,	300	
Maximum I ² t for fusing		t = 10 ms	$ \begin{array}{c} \text{No voltage} \\ \text{reapplied} \end{array} \text{ initial } T_J = T_J \text{ maximum} $	574		
	l ² t	t = 8.3 ms			524	A ² s
		t = 10 ms	100 % V _{RRM} reapplied		405	
		t = 8.3 ms			375	
Maximum I ² √t for fusing	I²√t	t = 0.1 to 10 ms, no voltage reapplied, $T_J = T_J$ maximum		5740	A²√s	
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), $I_{J} = I_{J}$ maximum		0.97	V	
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)})$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		1.24	
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), $I_{J} = I_{J}$ maximum		17.9	mΩ	
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		13.6	11122	
Maximum on-state voltage	V _{TM}	I _{pk} = 50 A, T _J = 25 °C		1.75	V	
Maximum holding current	I _H	T 05 °C 4	T _J = 25 °C, anode supply 6 V, resistive load		130	mA
Latching current	ΙL	1,1=25 6,8			200	

SWITCHING					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
	$V_{DRM} \leq 600 \ V$			200	A/μs
Maximum rate of rise	$V_{DRM} \leq 800 \ V$	dl/dt	$T_J = T_J$ maximum, $V_{DM} = Rated V_{DRM}$ Gate pulse = 20 V, 15 Ω , $t_D = 6 \mu s$, $t_r = 0.1 \mu s$ maximum	180	
of turned-on current –	$V_{DRM} \leq 1000 \; V$	ui/ut	Gate pulse = 20 V, 13 Ω , t_p = 6 μ s, t_r = 0.1 μ s maximum I_{TM} = (2 x rated dl/dt) A	160	
	$V_{DRM} \leq 1600 \; V$			150	
Typical turn-on time		t _{gt}	$T_J = 25 ^{\circ}\text{C}$, at rated V_{DRM}/V_{RRM} , $T_J = 125 ^{\circ}\text{C}$	0.9	
Typical reverse recovery time		t _{rr}	$T_J = T_J$ maximum, $I_{TM} = I_{T(AV)}$, $t_p > 200 \mu s$, $dI/dt = -10 A/\mu s$	4	μs
Typical turn-off time		t _q	$T_J=T_J$ maximum, $I_{TM}=I_{T(AV)},t_p>200~\mu s,V_R=100~V,dI/dt=$ - 10 A/µs, dV/dt = 20 V/µs linear to 67 % $V_{DRM},$ gate bias 0 V to 100 W	110	

Note

• t_q = 10 μs up to 600 V, t_q = 30 μs up to 1600 V available on special request

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise	dV/dt	T _J = T _J maximum linear to 100 % rated V _{DRM}	100	V/µs
of off-state voltage	uv/ut	T _J = T _J maximum linear to 67 % rated V _{DRM}	300 (1)	v/μS

Note

⁽¹⁾ Available with: dV/dt = 1000 V/µs, to complete code add S90 i.e. 16RIA120S90



TRIGGERING					
PARAMETER	SYMBOL	TES	T CONDITIONS	VALUES	UNITS
Maximum peak gate power	P _{GM}	$T_{.1} = T_{.1}$ maximum		8.0	W
Maximum average gate power	P _{G(AV)}	ıj = ıj maximum		2.0	
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum		1.5	Α
Maximum peak negative gate voltage	-V _{GM}	T _J = T _J maximum		10	V
		T _J = - 65 °C		90	
DC gate current required to trigger	I _{GT}	T _J = 25 °C	Maximum required gate trigger current/voltage are the lowest value which will trigger all units 6 V anode to cathode applied	60	mA
		T _J = 125 °C		35	
	V _{GT}	T _J = - 65 °C		3.0	
DC gate voltage required to trigger		T _J = 25 °C		2.0	V
		T _J = 125 °C		1.0	
DC gate current not to trigger	I _{GD}	T _J = T _J maximum, V _{DRM} = Rated value		2.0	mA
DC gate voltage not to trigger	V _{GD}	$T_J = T_J$ maximum, $V_{DRM} = Rated value$	Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.2	V

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES		UNITS	
Maximum operating junction and storage temperature range	T _J , T _{Stg}		-65 to +125		°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.	86		
Maximum thermal resistance, case to heat sink	R _{thCS}	Mounting surface, smooth, flat and greased	0.35		K/W	
			TO NUT	TO DEVICE		
			20 (27.5)	25	lbf ⋅ in	
Mounting torque		Lubricated threads (Non-lubricated threads)	0.23 (0.32)	0.29	kgf · m	
		(ton labilitation amount)	2.3 (3.1)	2.8	N·m	
Approximate weight			1	4	g	
Approximate weight			0.	49	oz.	
Case style		See dimensions - link at the end of datasheet	t TO-48 (TO-208AA))	

△R _{thJC} CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.21	0.15		
120°	0.25	0.25		
90°	0.31	0.34	$T_J = T_J$ maximum	K/W
60°	0.45	0.47		
30°	0.76	0.76		

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

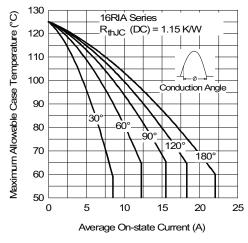


Fig. 1 - Current Ratings Characteristics

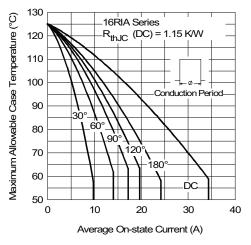


Fig. 2 - Current Ratings Characteristics

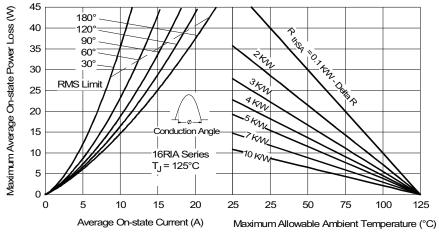


Fig. 3 - On-State Power Loss Characteristics

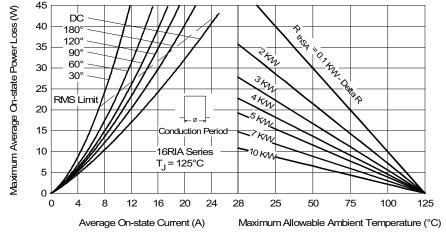


Fig. 4 - On-State Power Loss Characteristics

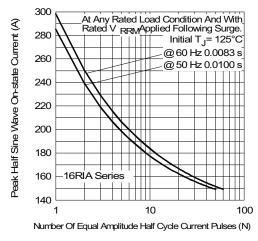


Fig. 5 - Maximum Non-Repetitive Surge Current

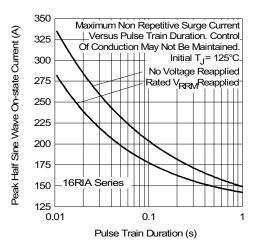


Fig. 6 - Maximum Non-Repetitive Surge Current

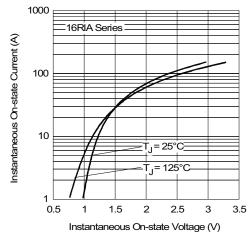


Fig. 7 - Forward Voltage Drop Characteristics

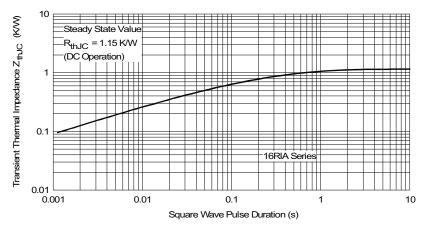


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



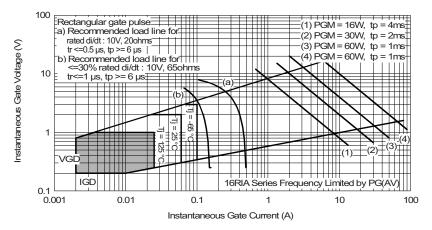
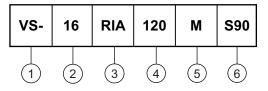


Fig. 9 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current code

3 - Essential part number

Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

None = stud base TO-48 (TO-208AA) 1/4" 28UNF-2A

M = stud base TO-48 (TO-208AA) M6 x 1

6 - Critical dV/dt:

None = 300 V/µs (standard value)

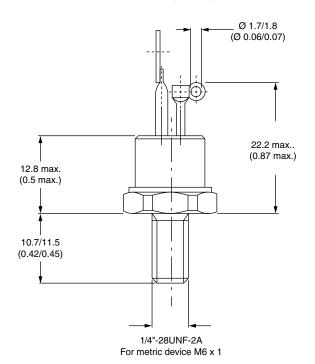
S90 = 1000 V/µs (special selection)

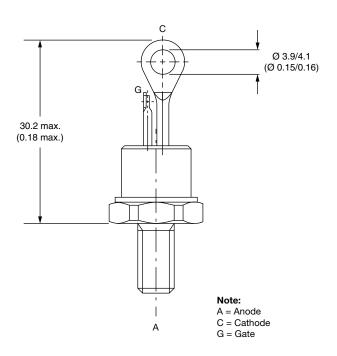
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95333		

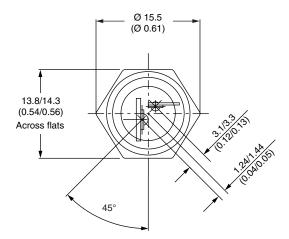


TO-208AA (TO-48)

DIMENSIONS in millimeters (inches)









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<u>VS-16RIA60M</u> <u>VS-16RIA100M</u> <u>VS-16RIA80M</u> <u>VS-16RIA10M</u> <u>VS-16RIA120M</u> <u>VS-16RIA120MS90</u> <u>VS-16RIA20M</u>

<u>VS-16RIA40M</u>